

Customer Code : \_\_\_\_\_

# DATASHEET

DAPU P/N: DPBF12500003

| Plot             |         |          | The Label              |
|------------------|---------|----------|------------------------|
| Drew             | Audited | Approved | Stamp, please! Thanks! |
|                  |         |          |                        |
| Date: 2017.08.31 |         |          |                        |

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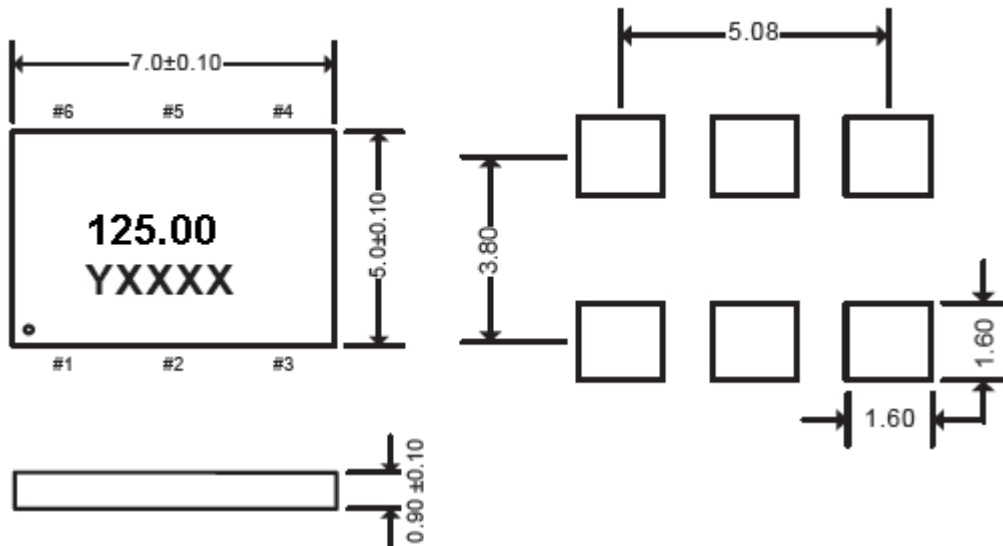
## 1、Electrical Parameters

| MODEL: DPBF12500003 |                                |          |                  |      |       |                    |   |
|---------------------|--------------------------------|----------|------------------|------|-------|--------------------|---|
| No.                 | Parameters                     | SYM.     | Electrical Spec. |      |       |                    | Notes   |
|                     |                                |          | Min.             | Typ. | Max.  | Units              |   |
| 1                   | Nominal Frequency              | FL       | 125.00           |      |       | MHz                |   |
| 2                   | Output Waveform                |          | LVDS             |      |       |                    |   |
| 3                   | Vdd                            |          | -0.5             |      | 4     | V                  |   |
| 4                   | Supply Voltage                 |          | 2.97             | 3.3  | 3.63  | V                  |   |
| 5                   | Frequency Stability            | F-stab   | -20              |      | +20   | $\times 10^{-6}$   | Inclusive of Initial tolerance, operating temperature, rated power supply voltage and load. |
| 6                   | Operating Temperature          | T-opr    | -40              | ~    | +85   | $^{\circ}\text{C}$ |   |
| 7                   | Storage Temperature            | T-stg    | -65              | ~    | +150  | $^{\circ}\text{C}$ |   |
| 8                   | Current Consumption            | Icc      | -                | 47   | 55    | mA                 |   |
| 9                   | OE Disable Supply Current      | I_OD     |                  |      | 35    | mA                 |   |
| 10                  | Standby Current                | I_std    |                  |      | 100   | $\mu\text{A}$      |   |
| 11                  | Rise/Full Time                 | Tr、 Tf   |                  | 495  | 700   | ps                 | 20%~80%   |
| 12                  | First Year Aging               |          | -2               |      | +2    | $\times 10^{-6}$   | @25 $^{\circ}\text{C}$  |
| 13                  | 10 Year Aging                  |          | -5               |      | +5    | $\times 10^{-6}$   | @25 $^{\circ}\text{C}$  |
| 14                  | Duty Cycle                     | DC       | 45               |      | 55    | %                  |   |
| 15                  | Differential Output Voltage    | VOD      | 250              | 350  | 450   | mV                 |   |
| 16                  | Output Disable Leakage Current |          | -                |      | 1     | $\mu\text{A}$      | OE=Low  |
| 17                  | Input Voltage High             | VIH      | 70%              | -    | -     | Vdd                | Pin 1   |
| 18                  | Input Voltage Low              | VIL      | -                | -    | 30%   | Vdd                | Pin 1   |
| 19                  | Input Pull-up Impedence        | Z_in     |                  | 100  | 250   | K $\Omega$         | Pin 1, OE logic high or logic low, or ST logic high   |
| 20                  | Start up Time                  | T_start  | -                | 6    | 10    | ms                 | Measured from the time Vdd reaches its rated minimum value                                  |
| 21                  | OE Enable/Disable Time         | T_oe     | -                | -    | 115   | ns                 |   |
| 22                  | Resume Time                    | T_resume |                  | 6    | 10    | ms                 |   |
| 23                  | RMS Period Jitter              | T_jitt   | -                | 1.2  | 1.7   | ps                 |   |
| 24                  | VOD Magnitude Change           |          |                  |      | 50    | mV                 |   |
| 25                  | Offset Voltage                 | VOS      | 1.125            | 1.2  | 1.375 | V                  |   |
| 26                  | VOS Magnitude Change           |          |                  |      | 50    | mV                 |   |
| 27                  | Phase Jitter                   | T_phj    | -                | 0.6  | 0.85  | ps                 | Integration bandwidth =12 kHz~20 MHz  |

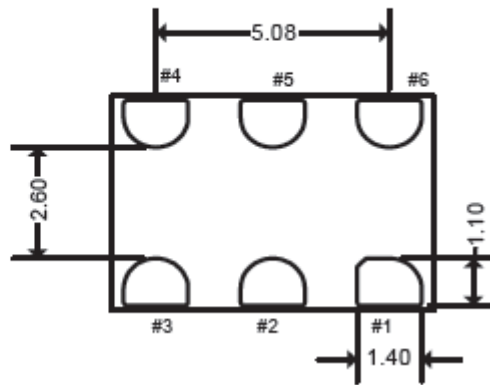


|    |                            |                          |
|----|----------------------------|--------------------------|
| 26 | Mechanical Shock           | MIL-STD-883F,Method 2002 |
|    | Mechanical Vibration       | MIL-STD-883F,Method 2007 |
|    | Temperature Cycle          | JESD22, Method A104      |
|    | Solderability              | MIL-STD-883F,Method 2003 |
|    | Moisture Sensitivity Level | MSL1 @260°C              |

## 2、Mechanical Structure(mm)



| Pin | Function        |
|-----|-----------------|
| #1  | $\overline{ST}$ |
| #2  | NC              |
| #3  | GND             |
| #4  | OUT+            |
| #3  | OUT-            |
| #4  | VDD             |



unit:mm

**Note1:** Tolerance  $\pm 0.2$ mm without mark

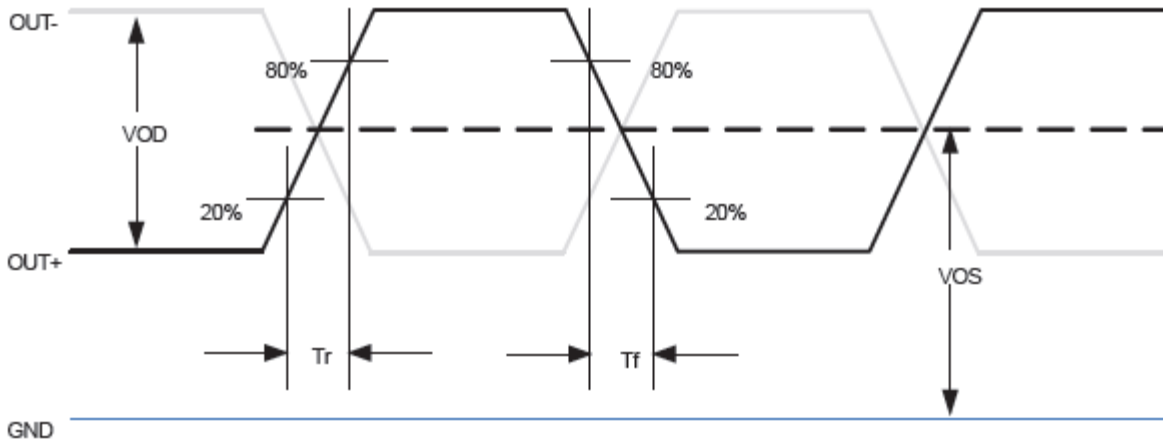
**Note2:** Referential weight 0.2g

**Note3:** Y denotes manufacturing origin and XXXX denotes manufacturing lot number. The value of “Y” will depend on the assembly location of the device

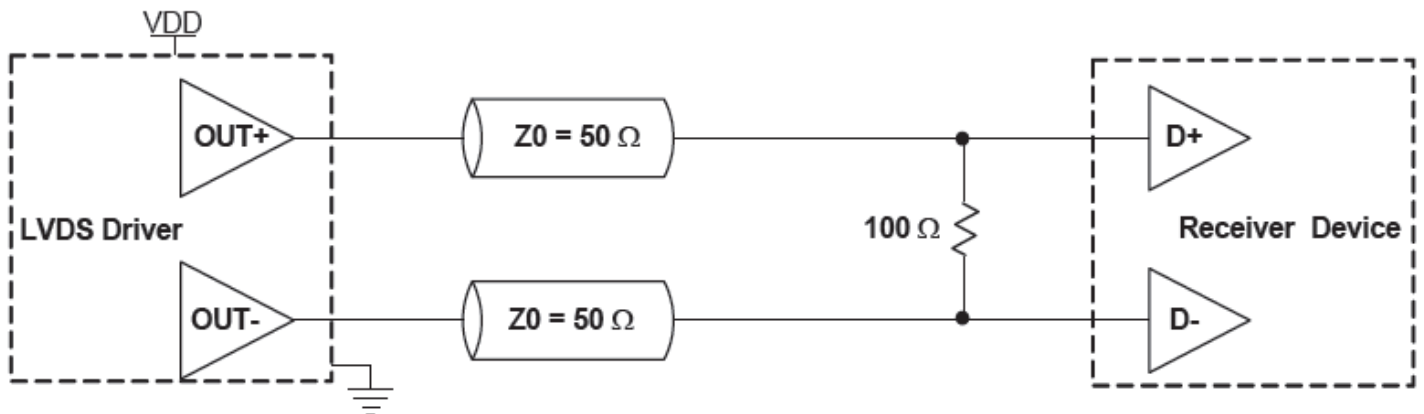
**Note4:** A capacitor of value 0.1 $\mu$  F or higher between Vdd and GND is required



### 3、Waveform Diagrams



### 4、Termination Diagrams



### 5、Package: Tape & Reel (mm)

